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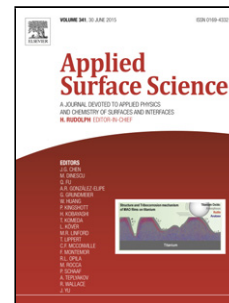
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Formation of InN atomic-size wires by simple N adsorption on the
In/Si(111)–(4×1) surface

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